捷多邦,专业PCB打样工厂,24小时加急出货



N-Channel Silicon MOSFET

2SK1887 **Ultrahigh-Speed Switching Applications**

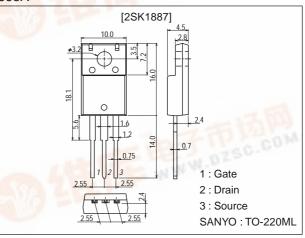
Features

- · Low ON resistance.
- · Ultrahigh-speed switching.
- · Low-voltage drive.
- · Micaless package facilitating easy mounting.

Package Dimensions

unit:mm





Specifications

Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	V _{DSS}		30	V
Gate-to-Source Voltage	V _{GSS}		±20	V
Drain Current (DC)	۱ _D		20	А
Drain Current (Pulse)	IDP	PW≤10µs, duty cycle≤1%	80	A
Allowable Power Dissipation	PD		2.0	W
	٢D	Tc=25°C	25	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta = 25°C

Symbol	Conditions	Ratings			Unit
		min	typ	max	Unit
V(BR)DSS	I _D =1mA, V _{GS} =0	30			V
V(BR)GSS	I _G =±100µA, V _{DS} =0	±20		-	V
IDSS	V _{DS} =30V, V _{GS} =0		1-5	100	μΑ
IGSS	V _{GS} =±16V, V _{DS} =0	10		±10	μA
VGS(off)	V _{DS} = 10V, I _D =1mA	1.0	4 07	2.0	V
yfs	V _{DS} =10V, I _D = 11A	9	14.5		S
R _{DS(on)}	I _D =11A, V _{GS} =1 <mark>0V</mark>		30	40	mΩ
R _{DS(on)}	ID=11A, VGS=4V		40	55	mΩ
	V(BR)DSS V(BR)GSS IDSS IGSS VGS(off) I yfs I RDS(on)	V(BR)DSS ID=1mA, VGS=0 V(BR)GSS IG=±100µA, VDS=0 IDSS VDS=30V, VGS=0 IGSS VGS=±16V, VDS=0 VGS(off) VDS=10V, ID=1mA yfs VDS=10V, ID=11A RDS(on) ID=11A, VGS=10V	V(BR)DSS ID=1mA, VGS=0 30 V(BR)GSS IG=±100µA, VDS=0 ±20 IDSS VDS=30V, VGS=0 10 IGSS VGS=±16V, VDS=0 10 VGS(off) VDS=10V, ID=1mA 1.0 I yfs VDS=10V, ID=11A 9 RDS(on) ID=11A, VGS=10V 10	Symbol Conditions min typ V(BR)DSS ID=1mA, VGS=0 30 30 V(BR)GSS IG=±100µA, VDS=0 ±20 IDSS VDS=30V, VGS=0 ±20 IGSS VGS=±16V, VDS=0 ±20 VGS(off) VDS=10V, ID=1mA 1.0 yfs VDS=10V, ID=11A 9 14.5 RDS(on) ID=11A, VGS=10V 30	Symbol Conditions min typ max V(BR)DSS ID=1mA, VGS=0 30 40 30 40 30 40 30 40 30 40 30 40 30 40 30 40 30 40 30 40 30 40 30 40 30 40 30 40 30 40 30 40 30 40 30 40

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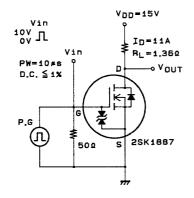
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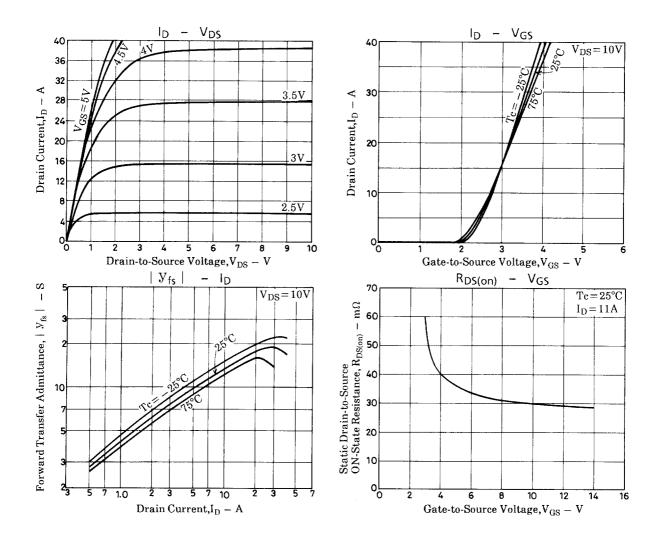
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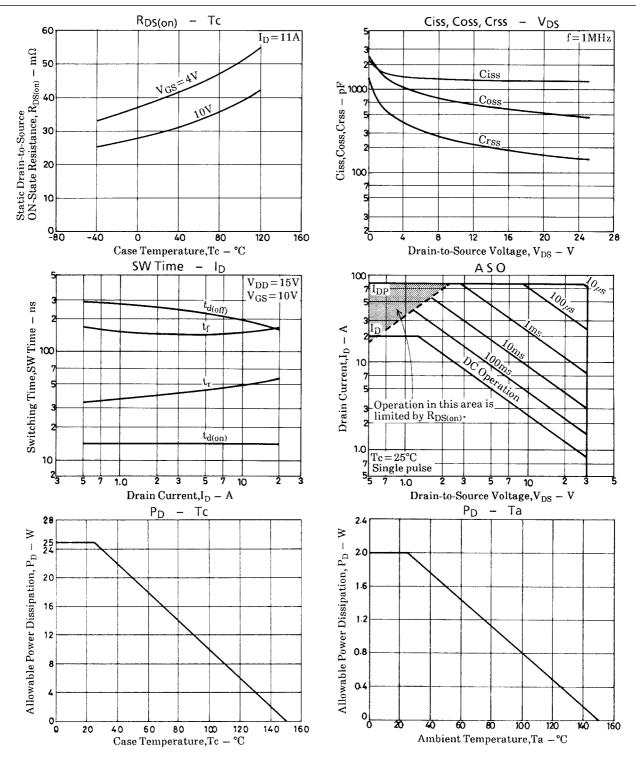
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Input Capacitance	Ciss	V _{DS} =10V, f=1MHz		1300		pF
Output Capacitance	Coss	V _{DS} =10V, f=1MHz		720		pF
Reverse Transfer Capacitance	Crss	V _{DS} =10V, f=1MHz		240		pF
Turn-ON Delay Time	^t d(on)	See specified Test Circuit		14		ns
Rise Time	tr	See specified Test Circuit		50		ns
Turn-OFF Delay Time	^t d(off)	See specified Test Circuit		290		ns
Fall Time	tf	See specified Test Circuit		150		ns
Diode Forward Voltage	V _{SD}	I _S =20A, V _{GS} =0		1.0	1.5	V

Switching Time Test Circuit





2SK1887



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